ASSP

CMOS

30 MHz 8-bit A/D Converter

MB40C238

■ DESCRIPTION

MB40C238 is a high-speed converter using a fast CMOS technology.

■ FEATURES

• Resolution : 8 bit

Linearity error : ±0.2% (standard)
 Differential linearity error : ±0.12% (standard)
 Maximum conversion rate : 30 MSPS (minimum)
 Power supply voltage : +3.0 V (single)
 Digital input voltage range : 3 V CMOS level

• Digital output voltage range : 3 V CMOS level compatible (tristate output)

• Analog input voltage range : 0 to 2.0 V (1.2 to 1.8 Vp-p)

Analog input capacitance : 15 pF (standard)

Power dissipation
 Additional features
 50 mW (standard: including reference current)
 VRT voltage adjustment amp (VRT = 1.2 to 2.0 V)

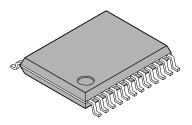
Power saving capacity (also reference current set to OFF: 0.5 mW or less)

High impedance output

Package : 24-pin SSOP

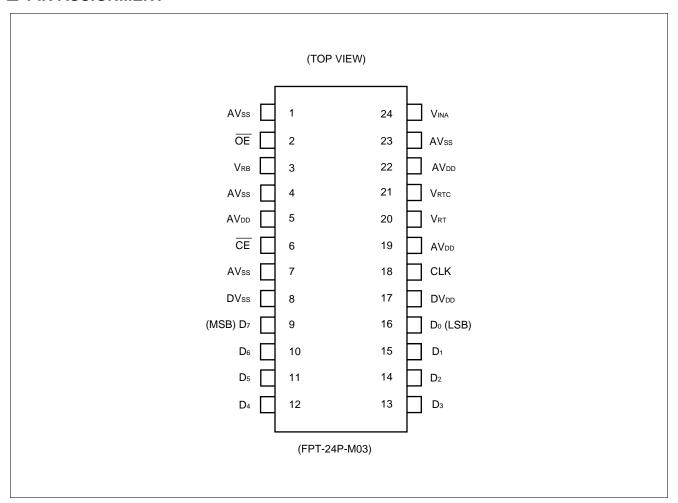
■ PACKAGE

24-pin Plastic SSOP



(FPT-24P-M03)

■ PIN ASSIGNMENT

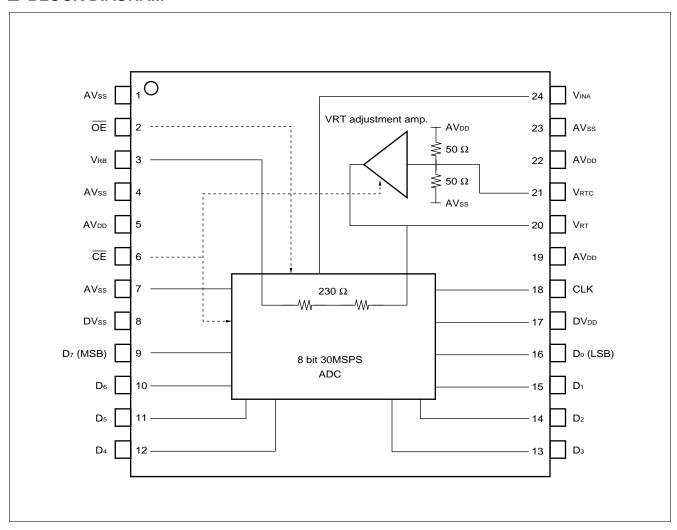


■ PIN DESCRIPTION

Pin No.	Symbol	Description
5, 19, 22	AVDD	Analog power supply (+3.0 V)
17	DV _{DD}	Digital power supply (+3.0 V)
1, 4, 7, 23	AVss	Analog power supply ground pin (0 V)
8	DVss	Digital power supply ground pin (0 V)
9, 10, 11, 12, 13, 14, 15, 16	D ₇ to D ₀	Digital output pin (D7: MSB, D0: LSB)
18	CLK	Clock input pin
24	VINA	A/D converter analog input pin Input range is VRB to VRT (0 to 1.5 V: standard)
21	VRTC	VRT voltage adjustment amp input pin (VRTC: 1.5 V is output when opened.)
20	V _{RT}	Reference voltage output pin on top side. The voltage fed to VRTC is output. (1.5 V: standard)
3	V _{RB}	Reference voltage input pin on bottom side (0 V: standard)
6	CE	Input pin for toggling standby function. Input high signal brings the ADC and reference voltage circuit.
2	OE	Input pin for toggling output high impedance function. Input high signal brings the ADC output high impedance state.

Note: The values in parentheses are standard.

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rat	Unit	
Farameter	Symbol	Min.	Max.	Oilit
Power supply voltage	AV _{DD} , DV _{DD}	-0.3	+7.0	V
Input voltage (analog/digital)	CLK, VINA, VRTC, VRB	-0.3	AVDD+0.3	V
Output voltage	D ₀ to D ₇	-0.3	DV _{DD} +0.3	V
Output voltage	V _{RT}	-0.3	AV _{DD} +0.3	V
Storage temperature	Tstg	-55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value			Unit	
raiametei	Symbol	Min.	Тур.	Max.		
	AV _{DD}	2.70	3.00	3.60	V	
Power supply voltage	DV _{DD}	2.70	3.00	3.60	V	
	AVDD — DVDD	0.0	_	0.2	V	
Analog input voltage	VINA	VRB	_	Vrt	V	
Analog reference voltage: T	VRTC	1.2	1.5	2.0	V	
Analog reference voltage: B	V _{RB}	0.0	_	0.8	V	
Analog reference voltage range	Vrt – Vrb	1.2	1.5	1.8	V	
Digital "H" level input voltage	Vihd	2.3	_	_	V	
Digital "L" level input voltage	VILD	_	_	0.5	V	
Digital input current	IID	_	_	5	μΑ	
Clock frequency	fclk	0.5	_	30	MHz	
"H" level minimum clock pulse width	tw +	16.0	_	_	ns	
"L" level minimum clock pulse width	tw -	16.0	_	_	ns	
Operating temperature range	Та	-20	_	+75	°C	

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics in Analog Section

 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, DV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, Ta = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

Parameter		Symbol	Value			Unit
		Symbol	Min.	Тур.	Max.	Unit
Resolution		_	_	8	_	bit
Linearity error	Conditional DC	LE	_	±0.20	±0.40	%
Differential linearity error	precision Vrt – Vrb = 1.5 V	DLE	_	±0.12	±0.20	%
Analog input capacity		CINA	_	15	_	pF
Reference input voltage (Top side) (VRTC opened)		VRTC	_	0.50 × AVDD	_	V
Reference output voltage (Top side)		VRT	_	VRTC	_	V
Reference current (Bottom side)		lпв	_	6.5	_	mA
Analog supply current		Aldd	_	14.0	34.0	mA
Digital supply current		DI _{DD}	_	3.0	7.0	mA
Standby supply current		ISTBA	_	100	_	μΑ
		Іѕтво	_	1	_	μΑ

2. DC Characteristics in Digital Section

 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, DV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, Ta = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

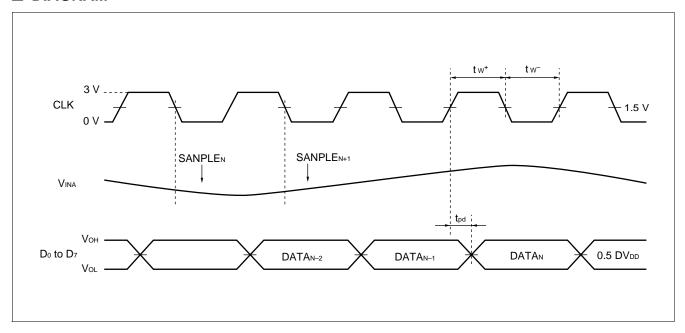
Doromotor	Cumbal	Value			I lmit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Digital "H" level output voltage	Vohd	2.4	_	DVpp	V
Digital "L" level output voltage	Vold	_	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	loL	_	_	1.6	mA

3. Switching Characteristics

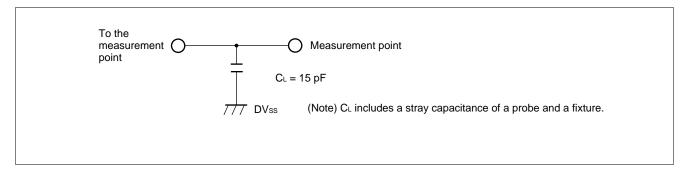
 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, DV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, Ta = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

Parameter	Symbol	Value			Unit
Farameter		Min.	Тур.	Max.	Onit
Maximum conversion rate	fs	30	_	_	MSPS
Digital output delay time	t pd	3	8	20	ns

■ DIAGRAM



■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



■ USAGE PRECAUTIONS

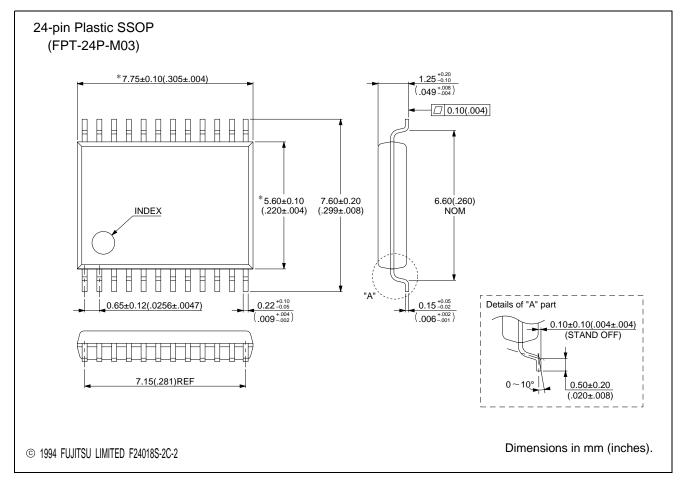
- Be sure to ground the pins of AV_{DD}, DV_{DD}, V_{RT} and V_{RB} via high-frequency capacitor. Place the high-frequency capacitor as close as possible to the pin.
- You can minimize the power supply current dissipation due to the internal logic indetermination by making the clock to 4CLK or higher.

MB40C238

■ ORDERING INFORMATION

Part number	Package	Remark
MB40C238PF	24-pin Plastic SSOP (FPT-24P-M03)	

■ PACKAGE DIMENSION



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